NSN 5961-01-222-6038



Transistor - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-222-6038 **Inclosure Material:** Metal **Overall Length:** 1.330 inches **Mounting Facility Quantity: Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-61 **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.687 inches **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 drain to gate voltage and 100.0 drain to source voltage **Current Rating Per Characteristic:** 38.00 amperes dark current **Power Rating Per Characteristic:** 150.0 watts total power dissipation **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:**

Yes - demil/mli

Fiig:

A110a0